## IN THE UNITED STATES PATENT AND TRADEMARK OFFICE

Priority Application Serial No	09/139,691
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Inventor	Michael J. Hermes
Assignee	Micron Technology, Inc.
Priority Group Art Unit	2812
Priority Examiner	
Attorney's Docket No	Ml22-2341
Title: Semiconductor Processing Methods of Forming Dyr	namic Random Access Memory
(DRAM) Circuitry	

## PRELIMINARY AMENDMENT ACCOMPANYING CONTINUATION APPLICATION

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## <u>AMENDMENTS</u>

## **Introductory Comments**

The present Preliminary Amendment is submitted in the Revised Amendment Format and therefore qualifies for waiver of provisions 37 CFR 1.121(a), (b), (c) and (d).